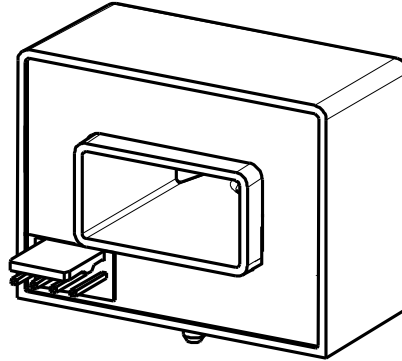


AS1V H01 SERIES

Current Sensor

Model Number:

AS1V 50 H01
AS1V 100 H01
AS1V 200 H01
AS1V 300 H01
AS1V 400 H01
AS1V 500 H01
AS1V 600 H01



For the electronic measurement of current: DC, AC, pulsed..., with galvanic Insulation between the primary and the secondary circuits.

Features

- ✧ Open loop current sensor using the Hall Effect.
- ✧ Output voltage is proportional to the supply voltage
- ✧ Galvanic Insulation between primary and secondary
- ✧ Insulating plastic case recognized according to UL 94-V0
- ✧ Supply voltage: +5V
- ✧ No insertion loss
- ✧ Small size
- ✧ Standards:
 - IEC 60664-1:2020
 - IEC 61800-5-1:2022
 - IEC 62109-1:2010

Applications

- ✧ AC variable speed
- ✧ Uninterruptible Power Supplies (UPS)
- ✧ Static converters for DC motor drives
- ✧ Switch Mode Power Supplies (SMPS)
- ✧ Power supplies for welding applications
- ✧ Battery management

Safety

This sensor must be used according to IEC 61800-5-1.

This sensor must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the following manufacture's operating instructions.

Caution, risk of electrical shock!



When operating the sensor, certain parts of the module can carry hazardous voltage (e.g., Primary busbar, power supply). Ignore this warning can lead to injury and/or cause serious damage.

This sensor is a built-in device, whose conducting parts must be inaccessible after installation. A protective housing or additional shield could be used.

Main supply must be able to be disconnected.

Absolute maximum ratings (not operating)

Parameter	Symbol	Unit	Value
Supply voltage	V_C	V	+ 6 V
Primary conductor temperature	T_B	°C	105
ESD rating, Human Body Model (HBM)	V_{ESD}	kV	4

- ※ Stress above these ratings may cause permanent damage.
- ※ Exposure to absolute maximum ratings for extended periods may degrade reliability.

Environmental and mechanical characteristics

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Ambient operating temperature	T_A	°C	-40		105	
Ambient storage temperature	T_S	°C	-40		125	
Mass	m	g		60		
Standards	IEC 60664-1, IEC 61800-5-1, IEC 62109-1					

Insulation coordination

Parameter	Symbol	Unit	Value	Comment
Rms voltage for AC insulation test @ 50Hz, 1min	V_d	kV	3.6	According to IEC 60664-1
Impulse withstand voltage 1.2/50μs	V_w	kV	6.6	
Clearance (pri.- sec.)	d_{cl}	mm	6.3	
Creepage distance (pri.- sec.)	d_{cp}	mm	7.3	
Plastic case	-	-	UL94-V0	
Comparative tracking index	CTI	PLC	3	
Application example	-	-	300V	Reinforced insulation, according to IEC 61800-5-1, IEC 62109-1 CAT III PD2
Application example	-	-	600V	Basic insulation, according to IEC 61800-5-1, IEC 62109-1 CAT III PD2

AS1V H01 SERIES

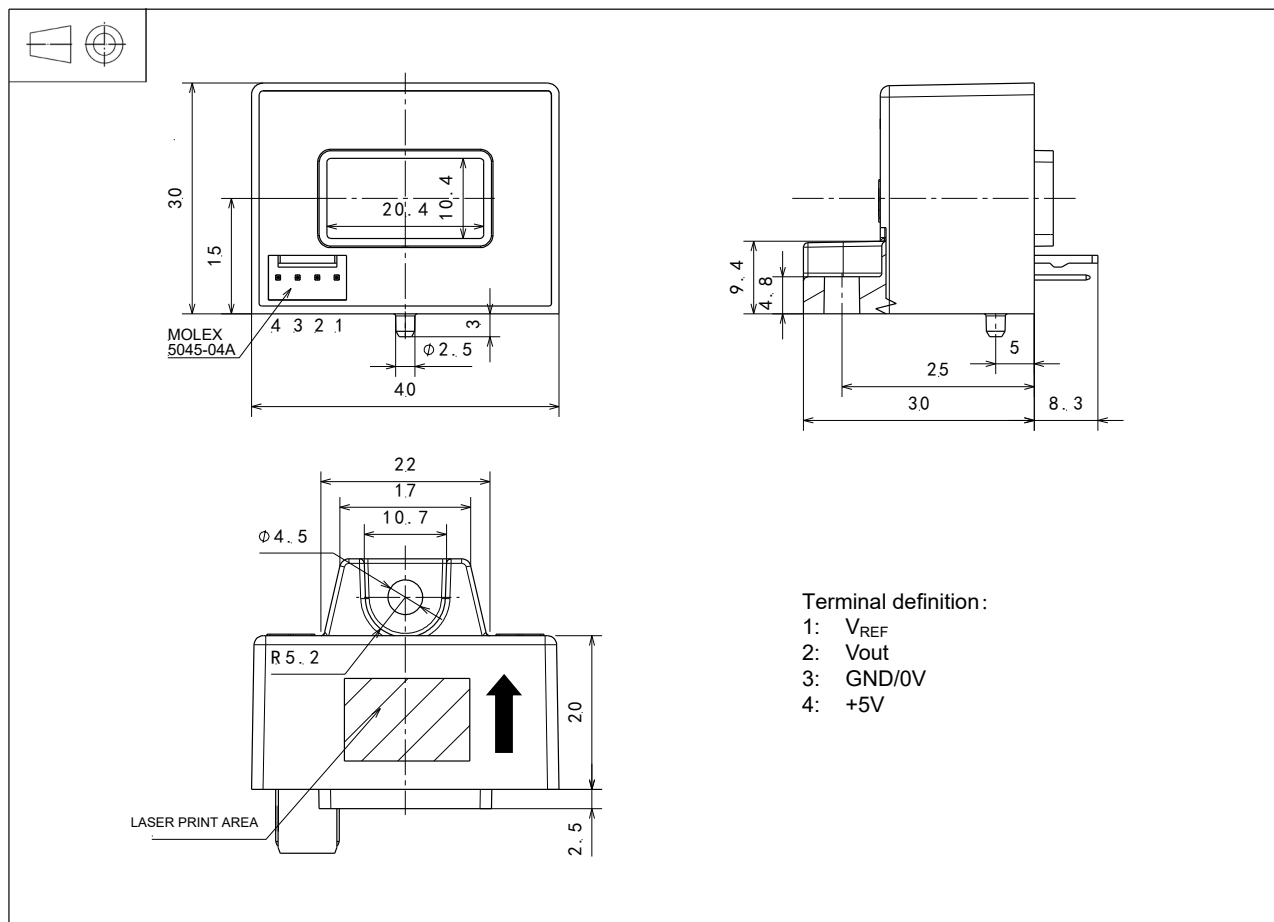
Electrical data

※ With $T_A = 25^\circ\text{C}$, $V_C = +5\text{V}$, $R_L = 10\text{k}\Omega$, unless otherwise noted.

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal rms current	I_{PN}	A	-50		50	AS1V 50 H01
			-100		100	AS1V 100 H01
			-200		200	AS1V 200 H01
			-300		300	AS1V 300 H01
			-400		400	AS1V 400 H01
			-500		500	AS1V 500 H01
			-600		600	AS1V 600 H01
Primary current, measuring range*1	I_{PM}	A	-150		150	AS1V 50 H01
			-300		300	AS1V 100 H01
			-600		600	AS1V 200 H01
			-900		900	AS1V 300...600 H01
Supply voltage	V_C	V	4.75	5.00	5.25	@ 5%
Current consumption	I_C	mA		12		
Output voltage (Analog) @ I_{PN}	V_{OUT}	V	$V_{OUT} = V_0 + G_{th} \times I_P$			
Reference voltage	V_{REF}	V	2.485	2.5	2.515	
Offset voltage	V_0	V	2.485	2.5	2.515	@ $I_P = 0\text{A}$
Load resistance	R_L	k Ω	10			
Current consumption	I_C	mA		12		
Electrical offset voltage	V_{OE}	mV	-10		10	
Temperature coefficient of V_{OE} *2	TCV_{OE}	mV	-10	± 6	10	@ $-40^\circ\text{C} \sim 105^\circ\text{C}$
Hysteresis offset voltage @ $I_P = 0$ after $1 \times I_{PN}$	V_{OM}	mV	-10		10	
Theoretical sensitivity	G_{th}	mV/A		12.5		AS1V 50 H01
				6.25		AS1V 100 H01
				3.125		AS1V 200 H01
				2.083		AS1V 300 H01
				1.563		AS1V 400 H01
				1.250		AS1V 500 H01
				1.041		AS1V 600 H01
Sensitivity error	ε_G	%	-0.5		0.5	Exclusive of V_{OE}
Temperature of G	TCG	%	-0.05		0.05	@ $-40^\circ\text{C} \sim 105^\circ\text{C}$
Linearity error 0... I_{PN}	ε_L	% of I_{PN}	-0.5		0.5	Exclusive of V_{OE}
Accuracy @ I_{PN}	X	% of I_{PN}	-1		1	Exclusive of V_{OE}
Response time @ 90% of I_{PN}	t_r	μs		3	5	
Frequency bandwidth(-3dB)	BW	kHz	50			

AS1V H01 SERIES

Dimensions (in mm. 1 mm = 0.0394 inch)



Mechanical characteristics

- General tolerance: ± 0.5 mm
- Connection of secondary: Molex 5045-04A
- Primary hole: 20.5mm x 10.5mm
- Sensor: 1pc $\Phi 4.5$ mm through hole
1pc M4 metal screws

Recommended fastening torque: 0.9 N•m ($\pm 10\%$)

Remarks

- V_{OUT} and I_P are in the same direction, when I_P flows in the direction of arrow.
- Temperature of the primary conductor should not exceed 105°C .
- Dynamic performances (di/dt and response time) are best with a single bar completely filling the primary hole.

This is a standard model. For different applications (measurement, secondary connections...), please contact CHIPSENSE.